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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/056,271	01/23/2002	Gary R. Janik	KLA-003 8560		
22888 7	590 06/15/2005		EXAMINER		
BEVER HOFFMAN & HARMS, LLP			STOCK JR, GORDON J		
TRI-VALLEY OFFICE					
1432 CONCA	NNON BLVD., BLDG.	G	ART UNIT	PAPER NUMBER	
LIVERMORE, CA 94550			2877 .		

DATE MAILED: 06/15/2005

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application	No.	Applicant(s)	
Office Action Summany	10/056,271		JANIK ET AL.	
Office Action Summary	Examiner		Art Unit	
The MAN INC DATE of the	Gordon J. S	*****	2877	
The MAILING DATE of this communication app Period for Reply	pears on the d	Over sheet with the c	orrespondence addr	ess
A SHORTENED STATUTORY PERIOD FOR REPL' THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.1 after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a repl - If NO period for reply is specified above, the maximum statutory period or - Failure to reply within the set or extended period for reply will, by statute Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	136(a). In no event ly within the statuto will apply and will e e, cause the applica	, however, may a reply be tim ry minimum of thirty (30) days expire SIX (6) MONTHS from ation to become ABANDONED	ely filed will be considered timely. the mailing date of this comm (35 U.S.C. § 133).	nunication.
Status				
1) Responsive to communication(s) filed on 31 M	1arch 2005.			
2a) ☐ This action is FINAL. 2b) ☑ This	s action is nor	n-final.		
3) Since this application is in condition for allowa	nce except fo	r formal matters, pro	secution as to the m	nerits is
closed in accordance with the practice under E	Ex parte Quay	/le, 1935 C.D. 11, 45	3 O.G. 213.	
Disposition of Claims				
4) ☐ Claim(s) 1.8-27.33-41.43-49.51 and 52 is/are 4a) Of the above claim(s) 22.23.25,26,38-40.45 5) ☐ Claim(s) is/are allowed. 6) ☐ Claim(s) 1.8-21.24.27.33-37.41.43.44.47.51 at 7) ☐ Claim(s) is/are objected to. 8) ☐ Claim(s) are subject to restriction and/or	5,46,48 and 4 nd 52 is/are r	is/are withdrawn fr	om consideration.	
Application Papers		•		
9) ☐ The specification is objected to by the Examine 10) ☑ The drawing(s) filed on 26 September 2004 is/s Applicant may not request that any objection to the Replacement drawing sheet(s) including the correct 11) ☐ The oath or declaration is objected to by the Ex	are: a)⊠ acc drawing(s) be tion is required	held in abeyance. See if the drawing(s) is obj	37 CFR 1.85(a). ected to. See 37 CFR	1.121(d).
Priority under 35 U.S.C. § 119				
12) Acknowledgment is made of a claim for foreign a) All b) Some * c) None of: 1. Certified copies of the priority document 2. Certified copies of the priority document 3. Copies of the certified copies of the priority application from the International Bureau * See the attached detailed Office action for a list	ts have been ts have been rity documen u (PCT Rule	received. received in Application ts have been receive 17.2(a)).	on No d in this National St	age
Attachment(s)				
1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948)	4) Interview Summary Paper No(s)/Mail Da		
3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) Paper No(s)/Mail Date) Notice of Informal Pa		52)

DETAILED ACTION

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Claim Rejections - 35 USC § 102

1. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.
- 2. Claims 51-52 are rejected under 35 U.S.C. 102(e) as being anticipated by Birdsley et al. (6,621,281).

As for claims 51 and 52, Birdsley in a sol die analysis of circuitry logic discloses the following: placing a test sample on a stage (Fig. 3: 310); directing an energy beam at a first location on the contaminant layer, the substrate layer that would contaminate BOX layer analysis, (Fig. 1: 160; Fig. 2: 260) via a laser etching device or an FIB device (col. 6, lines 22-25); which removes a first portion of the contaminant layer, substrate layer, to expose a first analysis area of the thin film, BOX layer (Fig. 2: 250) which the BOX layer is formed on a substrate, a thin layer of silicon (Fig. 1: 140); measuring the thin film at the first analysis area while the test sample is on the stage, wherein measuring the thin film comprises performing a contact-based electrical analysis, capacitive monitoring for analysis (col. 6, lines 15-22). Again, Birdsley discloses an energy beam source for directing an energy beam at the contaminant layer, substrate layer, to expose an analysis area on the thin film, the BOX layer (col. 6, lines 22-25; Fig. 2: 260, 250) and a thin film analysis module for measuring the thin film at the analysis area

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(Fig. 3: 330) comprising a contact based electrical analysis system, a capacitive monitoring system (col. 6, lines 15-22).

Claim Rejections - 35 USC § 103

- 3. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 4. Claims 1, 8, 14, 17, 18, 19, 20, 21, 24, 27, 33, 35, 36, 37, 41, 44, and 47 are rejected under 35 U.S.C. 103(a) as being unpatentable over Elliott et al. (5,669,979)-previously cited in view of Fukuda et al. (4,876,983)—previously cited.

As for claims 1, 27, 33, and 41, Elliott discloses in a photoreactive surface processing system: an energy beam (pulsed) source for directing an energy beam at a contaminant layer of a test sample on a stage to remove the layer from the test sample; a light scattering monitoring system to measure the cleaning of the surface (Fig. 15: 422, 518, 520, 436, 476, 414; col. 21, lines 25-40). The test sample may comprise a thin film (Fig. 13: substrate with implanted photoresist layer; col. 25, lines 25-30; col. 26, lines 1-10). He does not explicitly state that the monitor being a thin film analysis module for measuring a thin film. However, again, he teaches that thin film's may be laser cleaned (col. 25, lines 25-67; col. 26, lines 1-25) and that the monitor measures cleanliness (col. 21, lines 25-40). Therefore, it would be obvious to one of ordinary skill in the art at the time the invention was made that the monitor was a thin film analysis module for measuring thin films, for the monitor measures the cleanliness of laser cleaned thin film samples.

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Elliott discloses that the monitoring system comprising a light scattering system (col. 21, lines 30-35). And that Auger analysis may be used to identify contaminants (col. 55-60). He does not explicitly state that Auger analysis is a non-contact electrical system. Fukuda in a plasma operation apparatus suggests that Auger analysis is a non-contact system that deals with scattering (col. 11, lines 25-55). Therefore, it would be obvious to one of ordinary skill in the art at the time the invention was made that the system comprise a non-contact electrically based system such as Auger electronic spectroscopy to determine purity of the test area and therefore possible presence of residual contaminants.

As for claims 8 and 14, Elliott in view of Fukuda discloses everything as above (see claim 1). And Elliott discloses the light source may be a pulsed laser source such as an alexandrite source (col. 21, lines 13-15).

As for claim 17, Elliott in view of Fukuda discloses everything as above (see claim 1). And Elliott discloses a fiber may be used to transmit the laser light to the test region (col. 26, lines 20-30).

As for claim 18, Elliott in view of Fukuda discloses everything as above (see claim 1).

And Elliott discloses that the system may comprise a flashlamp (col. 11, lines 60-67).

As for claims 19 and 35, Elliott in view of Fukuda discloses everything as above (see claims 1 and 27 above). As for a non-functional region, Elliott does not explicitly state that the analysis area comprises a non-functional area. However, ion implantation is used to fabricate semiconductor devices; whereby, there would be areas of ion doping and area of no ion doping (col. 23, lines 5-55). Therefore, it would be obvious to one of ordinary skill in the art at the time

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the invention was made that the test sample would comprise areas of non-functionality and functionality for a test sample such as a wafer has areas that are ion doped and not ion doped.

As for claims 20 and 36, Elliott in view of Fukuda discloses everything as above (see claims 1 and 27 above). And Elliott discloses that the beam spot is 20 microns by 20 microns or larger in area (col. 10, lines 64-67).

As for claims 21, 24, 37, 44, and 47, Elliott in view of Fukuda discloses everything as above (see claims 1, 27 and 41). In addition, Elliott discloses the probe beam of the monitoring laser is approximately at the same position as the cleaning laser (Fig. 15: 518, 420, 428, 416). As for a second location of cleaning and monitoring, the wafer is scanned; thereby, multiple areas of exposure and measurement may be accomplished (Figs. 10a and 10b).

5. Claims 9-13, 15, 34, and 43 are rejected under 35 U.S.C. 103(a) as being unpatentable over Elliott et al. (5,669,979)—previously cited in view of Fukuda et al. (4,876,983)—previously cited further in view of Morris et al. (6,472,295)—previously cited.

As for claims 9-13, 15, 34, and 43, Elliot in view of Fukuda discloses everything as above (see claims 8, 33, and 41 above). In addition, Elliott discloses the use of a Nd:YAG pulsed laser operating at 532 nm, 355nm, 266nm, and 1064nm (col. 12, lines 13-20). As for the laser being a modulated continuous laser with a laser diode and being q-switched, Elliott is silent. However, Morris teaches in an apparatus for laser ablation teaches that a pulsed Nd:YAG laser comprises a diode and suggests that it is continuous made pulsed through modulation and q-switching (col. 2, lines 30-55). Therefore, it would be obvious to one of ordinary skill in the art at the time the invention was made that the system comprised a continuous laser made pulsed

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through modulation that is also q-switched and comprised a laser diode in order to provide lasing, control, and pulse modulation for the pulsed Nd:Yag laser.

6. Claim 16 is rejected under 35 U.S.C. 103(a) as being unpatentable over Elliott et al. (5,669,979)-previously cited in view of Fukuda et al. (4,876,983)—previously cited further in view of Haight et al. (6,333,485)-previously cited.

As for claim 16, Elliott in view of Fukuda discloses everything as above (see claim 1). However, Elliott is silent concerning the laser producing energy between 5 and 100 microjoules. Haight in a method for minimizing sample damage during laser ablation teaches of using a pulse energy between 10 nanojoules and 1 millijoule to prevent undesired damage to the material underneath the ablated surface (col. 1, lines 45-50; col. 3, lines 10-15). Therefore, it would be obvious to one of ordinary skill in the art at the time the invention was made to have the pulse energy between 5 and 100 microjoules, for an energy between 10 nanojoules and 1 millijoule prevents undesired damage to the material underneath the ablated surface.

Response to Arguments

7. Applicant's arguments with respect to the claims have been considered but are moot in view of the new ground(s) of rejection. As for the allowable subject matter mentioned in the previous action, Examiner apologizes for the inconvenience but upon further search a rejection of claims 51-52 has been made.

Fax/Telephone Numbers

If the applicant wishes to send a fax dealing with either a proposed amendment or a discussion with a phone interview, then the fax should:

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1) Contain either a statement "DRAFT" or "PROPOSED AMENDMENT" on the fax

cover sheet; and

2) Should be unsigned by the attorney or agent.

This will ensure that it will not be entered into the case and will be forwarded to the examiner as

quickly as possible.

Papers related to the application may be submitted to Group 2800 by Fax transmission. Papers should be faxed to Group 2800 via the PTO Fax machine located in Crystal Plaza 4. The

f apers should be jaxed to Group 2000 via the F1O Fax machine localed in Crystal Flaza 4. The form of such papers must conform to the notice published in the Official Gazette, 1096 OG 30

(November 15, 1989). The CP4 Fax Machine number is: (703) 872-9306

Any inquiry concerning this communication or earlier communications from the examiner

should be directed to Gordon J. Stock whose telephone number is (571) 272-2431.

The examiner can normally be reached on Monday-Friday, 10:00 a.m. - 6:30 p.m.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's

supervisor, Gregory J. Toatley, Jr., can be reached at 571-272-2800 ext 77.

Information regarding the status of an application may be obtained from the Patent

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gs

June 8, 2005

andra V. Smith

Primary Examin

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